



Standard Rectifier Module

$$V_{RRM} = 1600\text{ V}$$

$$I_{FAV} = 560\text{ A}$$

$$V_F = 0,98\text{ V}$$

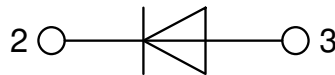
Single Diode

Part number

MDO500-16N1



Backside: isolated



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: Y1

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Base plate: Copper internally DCB isolated
- Advanced power cycling

Disclaimer Notice

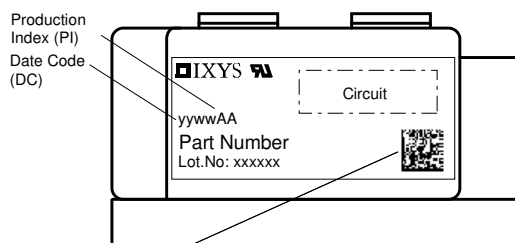
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| Rectifier | | | | Ratings | | | |
|--------------|--|-----------------------------------|---------|-------------------------|-------|-------|-------------------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V_{RSM} | max. non-repetitive reverse blocking voltage | | | $T_{VJ} = 25^{\circ}C$ | | 1700 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | | | $T_{VJ} = 25^{\circ}C$ | | 1600 | V |
| I_R | reverse current | $V_R = 1600 V$ | | $T_{VJ} = 25^{\circ}C$ | | 1 | mA |
| | | $V_R = 1600 V$ | | $T_{VJ} = 140^{\circ}C$ | | 30 | mA |
| V_F | forward voltage drop | $I_F = 500 A$ | | $T_{VJ} = 25^{\circ}C$ | | 1,09 | V |
| | | $I_F = 1000 A$ | | | | 1,24 | V |
| | | $I_F = 500 A$ | | $T_{VJ} = 125^{\circ}C$ | | 0,98 | V |
| | | $I_F = 1000 A$ | | | | 1,17 | V |
| I_{FAV} | average forward current | $T_C = 85^{\circ}C$ | | $T_{VJ} = 140^{\circ}C$ | | 560 | A |
| $I_{F(RMS)}$ | RMS forward current | 180° sine | d = 0.5 | | | | A |
| V_{F0} | threshold voltage | } for power loss calculation only | | $T_{VJ} = 140^{\circ}C$ | | 0,80 | V |
| r_F | slope resistance | | | | | 0,38 | mΩ |
| R_{thJC} | thermal resistance junction to case | | | | | 0,072 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | | 0,024 | | K/W |
| P_{tot} | total power dissipation | | | $T_C = 25^{\circ}C$ | | 1600 | W |
| I_{FSM} | max. forward surge current | t = 10 ms; (50 Hz), sine | | $T_{VJ} = 45^{\circ}C$ | | 15,0 | kA |
| | | t = 8,3 ms; (60 Hz), sine | | $V_R = 0 V$ | | 16,2 | kA |
| | | t = 10 ms; (50 Hz), sine | | $T_{VJ} = 140^{\circ}C$ | | 12,8 | kA |
| | | t = 8,3 ms; (60 Hz), sine | | $V_R = 0 V$ | | 13,8 | kA |
| I^2t | value for fusing | t = 10 ms; (50 Hz), sine | | $T_{VJ} = 45^{\circ}C$ | | 1,13 | MA ² s |
| | | t = 8,3 ms; (60 Hz), sine | | $V_R = 0 V$ | | 1,09 | MA ² s |
| | | t = 10 ms; (50 Hz), sine | | $T_{VJ} = 140^{\circ}C$ | | 812,8 | kA ² s |
| | | t = 8,3 ms; (60 Hz), sine | | $V_R = 0 V$ | | 788,8 | kA ² s |
| C_J | junction capacitance | $V_R = 400 V; f = 1 MHz$ | | $T_{VJ} = 25^{\circ}C$ | | 762 | pF |



| Package Y1 | | | Ratings | | | |
|---------------|--|----------------------|---------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 600 | A |
| T_{VJ} | virtual junction temperature | | -40 | | 140 | °C |
| T_{op} | operation temperature | | -40 | | 125 | °C |
| T_{stg} | storage temperature | | -40 | | 125 | °C |
| Weight | | | | 650 | | g |
| M_D | mounting torque | | 4,5 | | 7 | Nm |
| M_T | terminal torque | | 11 | | 13 | Nm |
| $d_{Spp/App}$ | creepage distance on surface striking distance through air | terminal to terminal | 16,0 | | | mm |
| $d_{Spb/Apb}$ | | terminal to backside | 25,0 | | | mm |
| V_{ISOL} | isolation voltage | t = 1 second | 4800 | | | V |
| | | t = 1 minute | 4000 | | | V |



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MDO500-16N1 | MDO500-16N1 | Box | 2 | 464813 |

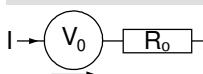
| Similar Part | Package | Voltage class |
|--------------|---------|---------------|
| MDO500-12N1 | Y1-2-CU | 1200 |
| MDO500-14N1 | Y1-2-CU | 1400 |
| MDO500-18N1 | Y1-2-CU | 1800 |
| MDO500-20N1 | Y1-2-CU | 2000 |

| | | |
|-------------|---------|------|
| MDO500-22N1 | Y1-2-CU | 2200 |
|-------------|---------|------|

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 140^{\circ}C$

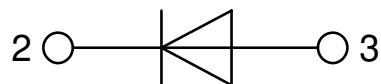
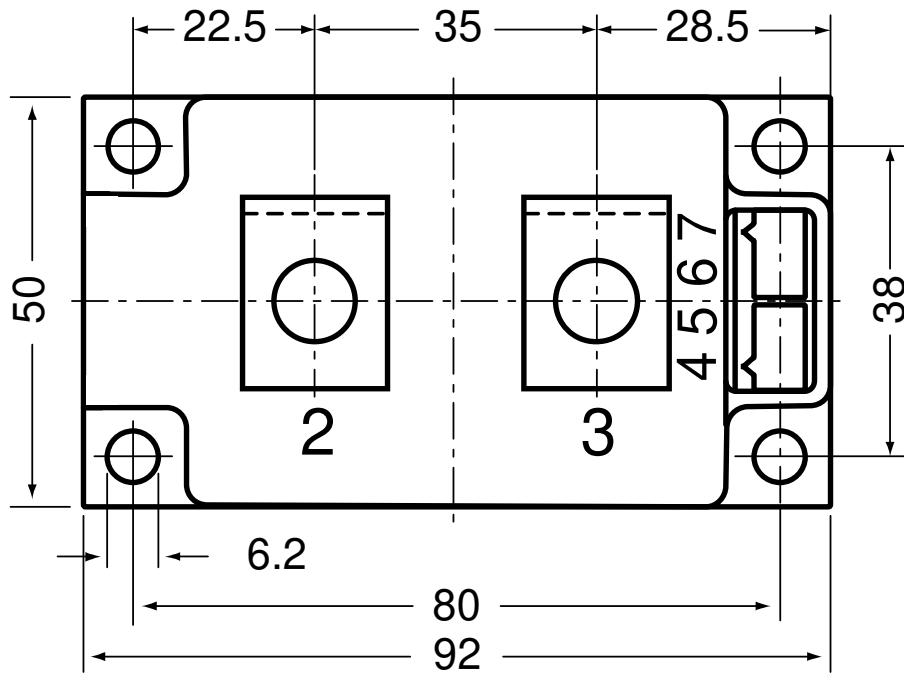
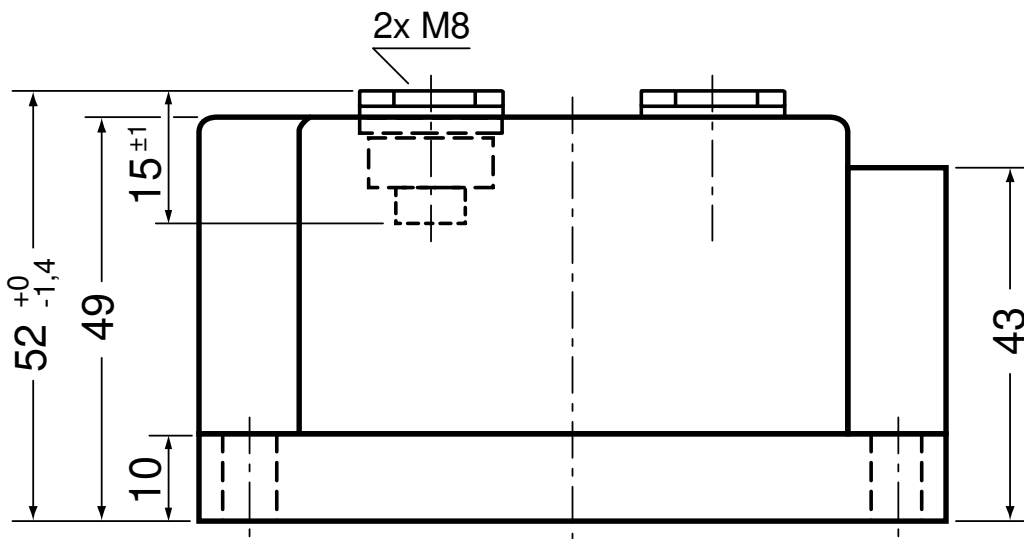


Rectifier

| | | | |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage | 0,8 | V |
| $R_{0\ max}$ | slope resistance * | 0,19 | mΩ |



Outlines Y1





Rectifier



Fig. 1 Surge overload current
 I_{FSM} : Crest value, t : duration



Fig. 2 I^2t versus time (1-10 ms)

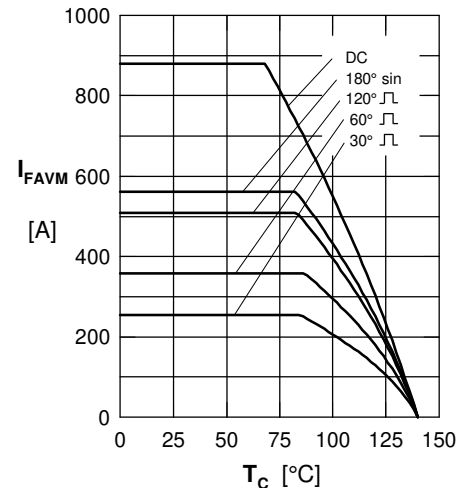


Fig. 3 Maximum forward current at case temperature

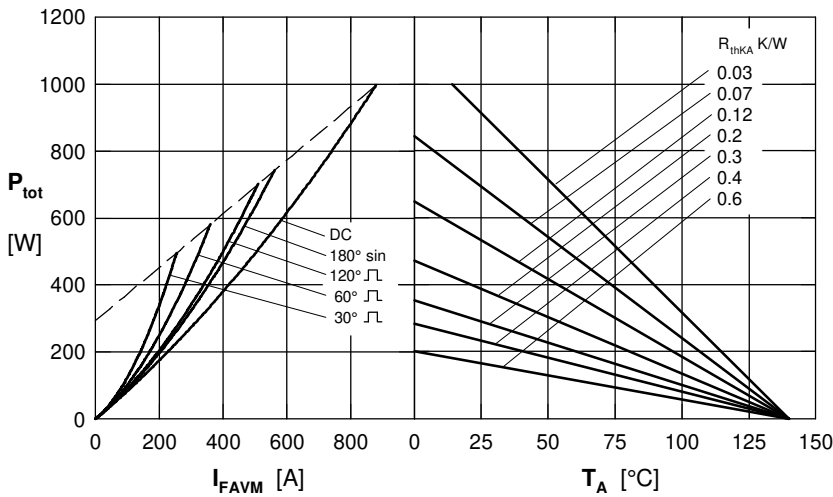


Fig. 4 Power dissipation vs. forward current and ambient temperature

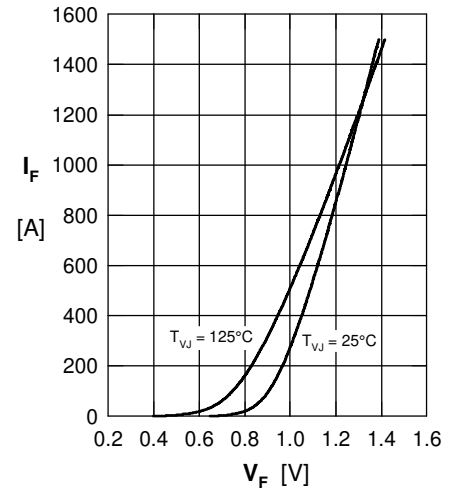


Fig. 5 Forward current I_F versus V_F

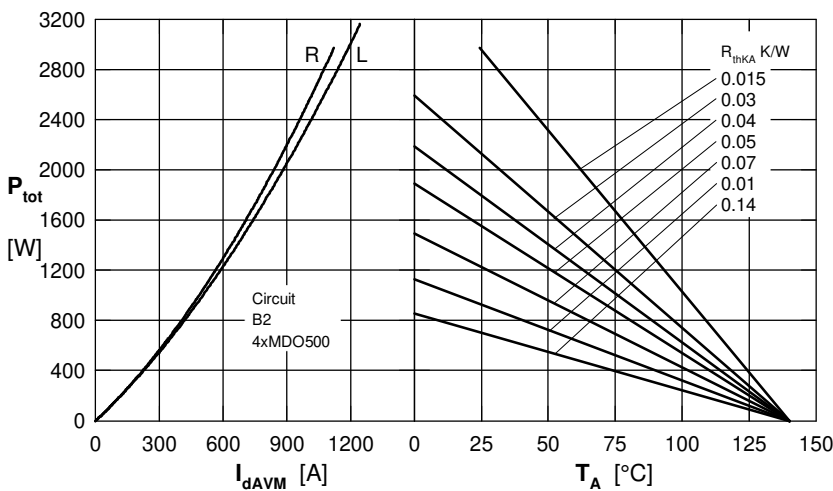


Fig. 6 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient temperature. R = resistive load, L = inductive load



Rectifier

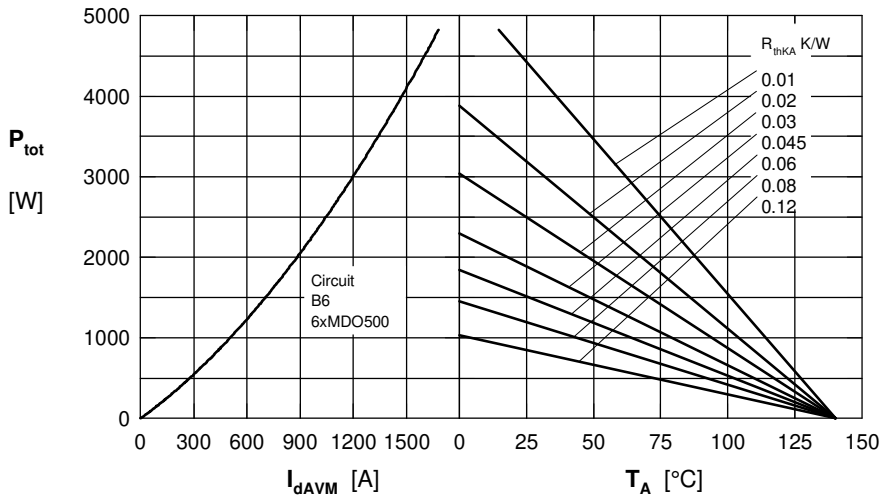


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

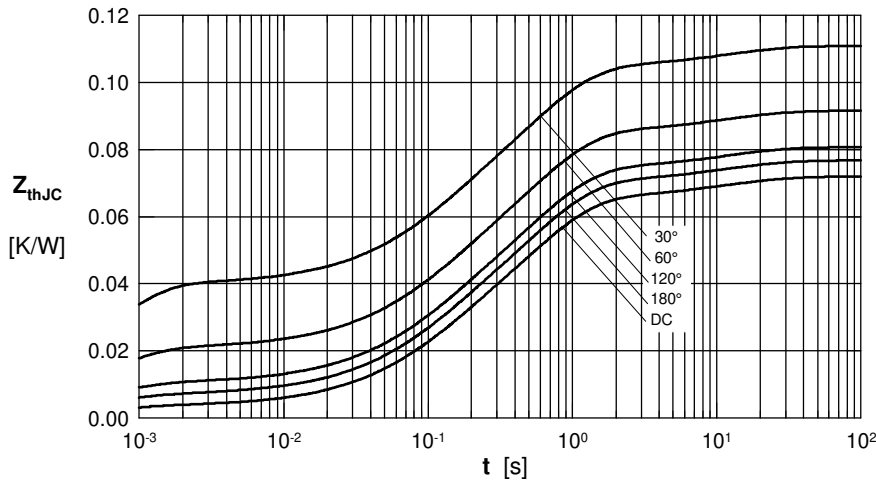


Fig. 7 Transient thermal impedance junction to case

R_{thJC} for various conduction angles d:

| d | R_{thJC} (K/W) |
|------|------------------|
| DC | 0.072 |
| 180° | 0.0768 |
| 120° | 0.081 |
| 60° | 0.092 |
| 30° | 0.111 |

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.0035 | 0.0054 |
| 2 | 0.0186 | 0.098 |
| 3 | 0.0432 | 0.54 |
| 4 | 0.0067 | 12 |

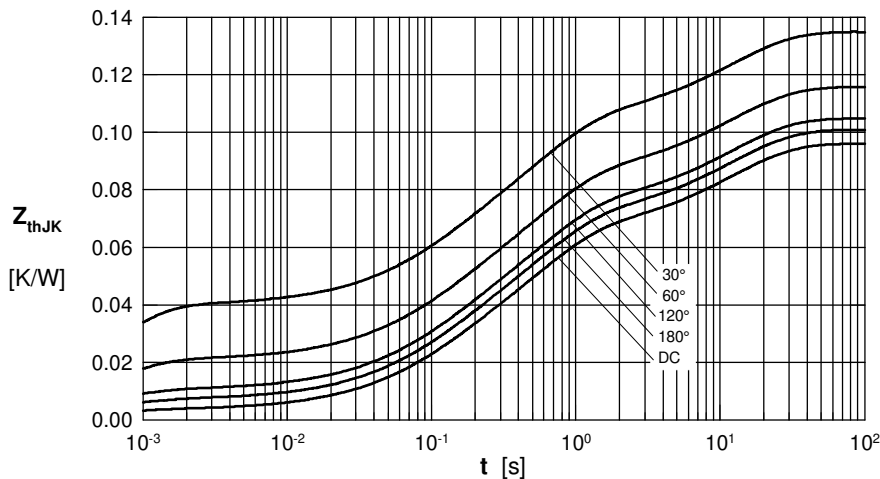


Fig. 8 Transient thermal impedance junction to heatsink

R_{thJK} for various conduction angles d:

| d | R_{thJK} (K/W) |
|------|------------------|
| DC | 0.096 |
| 180° | 0.1 |
| 120° | 0.105 |
| 60° | 0.116 |
| 30° | 0.135 |

Constants for Z_{thJK} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.0035 | 0.0054 |
| 2 | 0.0186 | 0.098 |
| 3 | 0.0432 | 0.54 |
| 4 | 0.0067 | 12 |
| 5 | 0.024 | 12 |